



# HiPerFRED

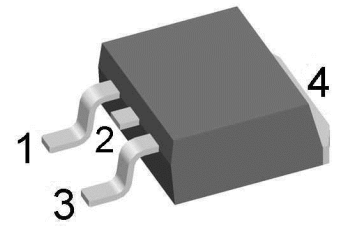
$V_{RRM}$	=	600 V
$I_{FAV}$	=	30 A
$t_{rr}$	=	35 ns

High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Single Diode

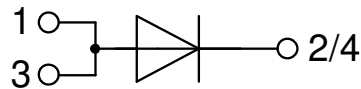
Part number

**DSEP29-06AS**

Marking on Product: DSEP29-06AS



Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

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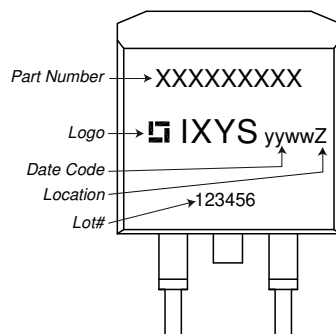


Fast Diode				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			600	V	
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			600	V	
$I_R$	reverse current, drain current	$V_R = 600 V$	$T_{VJ} = 25^{\circ}C$		250	$\mu A$	
		$V_R = 600 V$	$T_{VJ} = 150^{\circ}C$		1	mA	
$V_F$	forward voltage drop	$I_F = 30 A$	$T_{VJ} = 25^{\circ}C$		1.61	V	
		$I_F = 60 A$			1.94	V	
		$I_F = 30 A$	$T_{VJ} = 150^{\circ}C$		1.26	V	
		$I_F = 60 A$			1.56	V	
$I_{FAV}$	average forward current	$T_C = 135^{\circ}C$ rectangular $d = 0.5$	$T_{VJ} = 175^{\circ}C$		30	A	
$V_{FO}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 175^{\circ}C$		0.91	V	
$r_F$	slope resistance				9.4	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.9	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W	
$P_{tot}$	total power dissipation		$T_C = 25^{\circ}C$		165	W	
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$		250	A	
$C_J$	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		26	pF	
$I_{RM}$	max. reverse recovery current	} $I_F = 30 \text{ A}; V_R = 300 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^{\circ}C$		6	A	
			$T_{VJ} = 100^{\circ}C$		10	A	
$t_{rr}$	reverse recovery time		$T_{VJ} = 25^{\circ}C$		35	ns	
			$T_{VJ} = 100^{\circ}C$		100	ns	



Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				1.5		g
$F_C$	mounting force with clip		20		60	N

**Product Marking**



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP29-06AS-TRL	DSEP29-06AS	Tape & Reel	800	499498
Alternative	DSEP29-06AS-TUB	DSEP29-06AS	Tube	50	473537

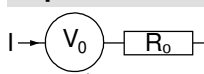
Similar Part	Package	Voltage class
DSEP29-06A	TO-220AC (2)	600
DSEP30-06A	TO-247AD (2)	600
DSEP30-06B	TO-247AD (2)	600
DSEP30-06BR	ISOPLUS247 (2)	600

DHG30I600PA	TO-220AC (2)	600
DHG30I600HA	TO-247AD (2)	600
DHG30IM600PC	TO-263AB (D2Pak) (2)	600

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 175^{\circ}C$



**Fast Diode**

$V_{0\ max}$	threshold voltage	0.91	V
$R_{0\ max}$	slope resistance *	6.1	mΩ

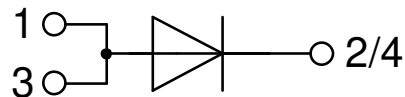


**Outlines TO-263 (D2Pak)**



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

*All dimensions conform with and/or within JEDEC standard.*



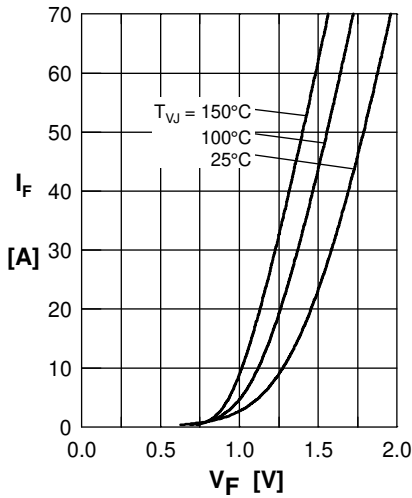
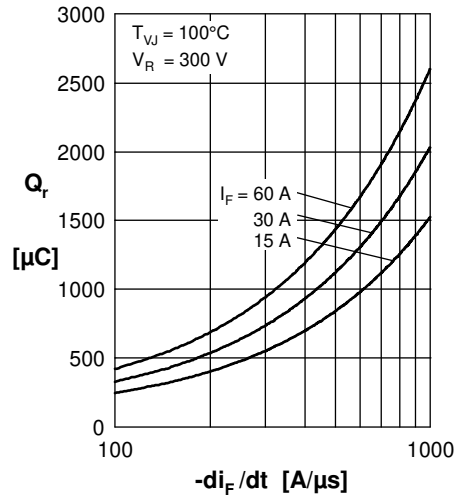
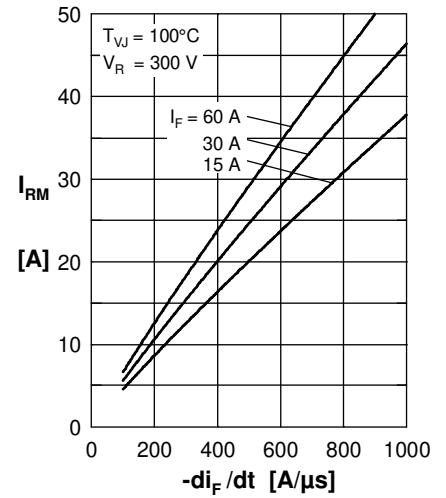
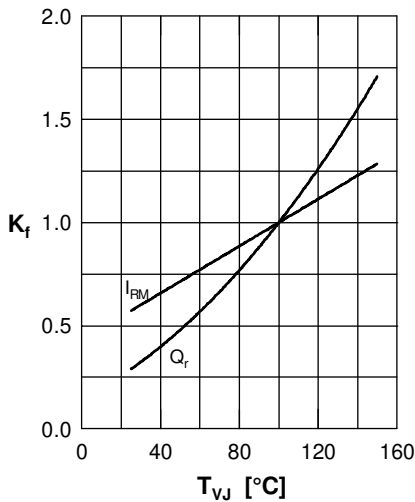
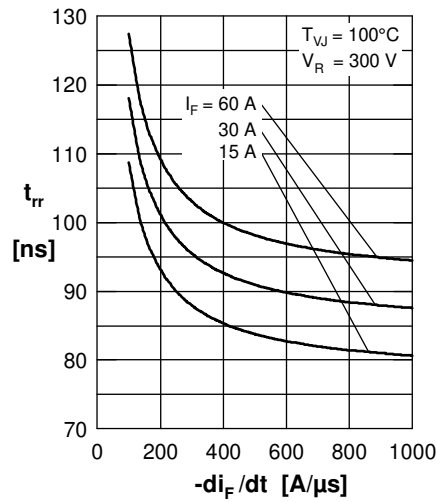
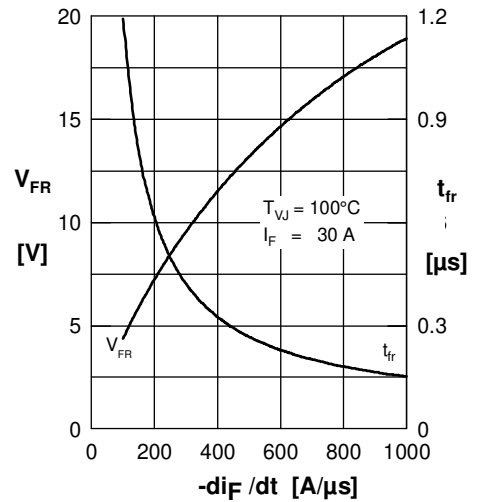
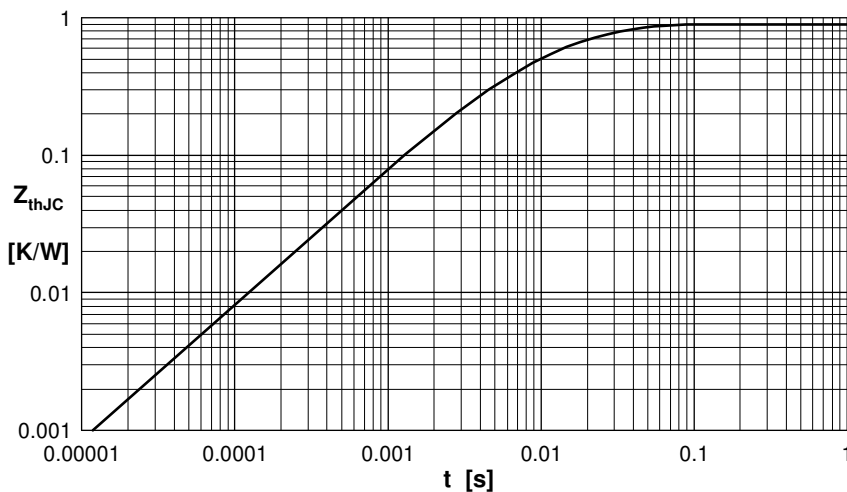
**Fast Diode**

 Fig. 1 Forward current  $I_F$  versus  $V_F$ 

 Fig. 2 Typ. reverse recov. charge  $Q_r$  versus  $-di_F/dt$ 

 Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$ 

 Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ 

 Fig. 5 Typ. recovery time  $t_{rr}$  versus  $-di_F/dt$ 

 Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$ 


Fig. 7 Transient thermal impedance junction to case

 Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.030	0.001
2	0.080	0.030
3	0.300	0.006
4	0.490	0.060